

Specifications

Part Number	IRFS7762TRLPBF
Manufacturer	International Rectifier (Infineon Technologies)
Description	MOSFET N-CH 75V 104A D2PAK
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2550 pcs Stock
Vgs(th) (Max) @ Id	3.7V @ 100μA
Vgs (Max)	±20V
Technology	MOSFET (Metal Oxide)
Supplier Device Package	D²PAK (TO-263AB)
Series	HEXFET®, StrongIRFET™
Rds On (Max) @ Id, Vgs	6.7 mOhm @ 51A, 10V
Power Dissipation (Max)	140W (Tc)
Packaging	Original-Reel®
Package / Case	TO-263-3, D²Pak (2 Leads + Tab), TO-263AB
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	4440pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	130nC @ 10V
FET Type	N-Channel
FET Feature	-
Drive Voltage (Max Rds On, Min Rds On)	6V, 10V
Drain to Source Voltage (Vdss)	75V
Current - Continuous Drain (Id) @ 25°C	85A (Tc)

In:

YIC International Co., Limited.

IRFS820
SEC
IRFS820 SEC



IRFS7762PBF
Infineon Technologies
MOSFET N-CH 75V 104A D2PAK



IRFS7787TRL PBF
Infineon Technologies
MOSFET N-CH 75V 76A D2PAK



IRFS7734-7PPBF
Infineon Technologies
MOSFET N-CH 75V 183A D2PAK



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More

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